



产品数据手册 Product Datasheet 版本 Ver 22.03

TG5000SG45ZF-P200

压接型 IGBT 模块 Press-pack IGBT Module

初版 Preliminary

关键参数		Key Parameters	
V_{CES}		4500	V
$V_{CE(sat)}$	Typ.	2.40	V
I_C	Max.	5000	A
$I_{C(RM)}$	Max.	10000	A

典型应用	Typical Applications
● 柔直换流阀	MMC-HVDC Valve
● 直流断路器	DC Breaker
● 海上风电	Off-shore Wind Power
● 大型工业传动	Large-scale Industrial Drive

特点	Features
● 双面散热	Double-side Cooling
● 失效短路	Short-circuit Failure Mode
● 高热循环能力	High Thermal Cycling Capability
● 低杂散电感	Low Stray Inductance

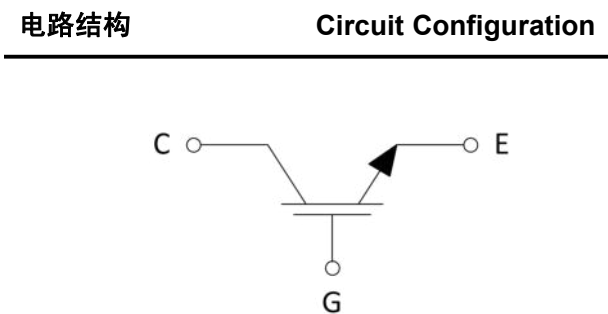


图 1. 电路结构
Fig. 1 Circuit configuration

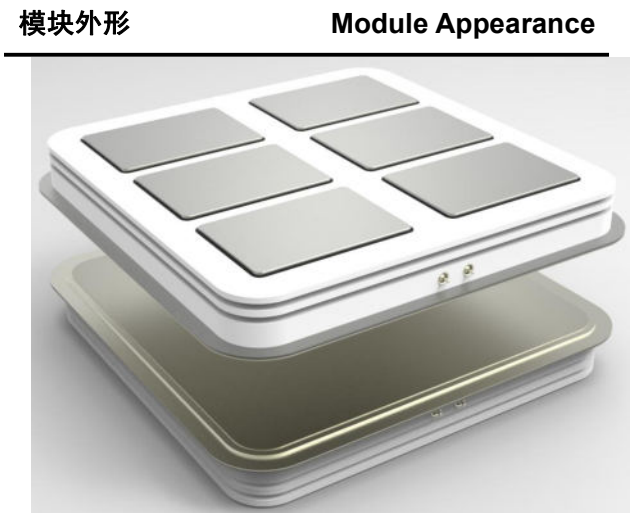


图 2. 模块外形
Fig. 2 Module appearance

模块标签说明	Module Label Code Instruction	
 18BC00670027	数据位置 Data position	数据内容 Content of data
	1—8	模块批次号 Module batch number
	9—12	模块序列号 Module serial number

最大额定值

Absolute Maximum Ratings

符号 Symbol	参数名称 Parameter	测试条件 Test Conditions	数值 Value	单位 Unit
V_{CES}	集电极-发射极电压 Collector-emitter voltage	$V_{GE} = 0V, T_C = 25\text{ }^{\circ}\text{C}$	4500	V
V_{GES}	栅极-发射极电压 Gate-emitter voltage	$T_C = 25\text{ }^{\circ}\text{C}$	± 20	V
I_C	集电极电流 Collector-emitter current	$T_C = 90\text{ }^{\circ}\text{C}$	5000	A
$I_{C(PK)}$	集电极峰值电流 Peak collector current	$t_P = 1\text{ms}$	10000	A



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热和机械数据

Thermal & Mechanical Data

符号 Symbol	参数名称 Parameter	测试条件 Test Conditions	最小值 Min.	典型值 Typ.	最大值 Max.	单位 Unit
$R_{th(J-C)} \text{ IGBT}$	IGBT 结壳热阻 Thermal resistance – IGBT	双面散热 Double-side cooling		1.5		K / kW
$R_{th(C-H)} \text{ IGBT}$	接触热阻(IGBT) Thermal resistance – case to heatsink (IGBT)	压装力 85kN Clamping Force 85kN		0.5		K / kW
T_{vj}	工作结温 Operating junction temperature				125	°C
T_{stg}	存储温度 Storage temperature range		-40		125	°C
M	压装力 Clamping Force		85		100	kN

电特性值
Electrical Characteristics

 除非特别声明, 否则 $T_C = 25\text{ }^{\circ}\text{C}$
 $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise stated

符号 Symbol	参数名称 Parameter	条件 Test Conditions	最小值 Min.	典型值 Typ.	最大值 Max.	单位 Unit
I_{CES}	集电极截止电流 Collector cut-off current	$V_{GE} = 0V, V_{CE} = V_{CES}$			1	mA
		$V_{GE} = 0V, V_{CE} = V_{CES}, T_C = 125\text{ }^{\circ}\text{C}$		35	100	mA
I_{GES}	栅极漏电流 Gate leakage current	$V_{GE} = \pm 20V, V_{CE} = 0V$			500	nA
$V_{GE(th)}$	栅极-发射极阈值电压 Gate threshold voltage	$I_C = 500mA, V_{GE} = V_{CE}$	5.5	6.0	6.5	V
$V_{CE(sat)}$	集电极-发射极饱和电压 Collector-emitter saturation voltage	$V_{GE} = 15V, I_C = 5000A$		2.40		V
		$V_{GE} = 15V, I_C = 5000A, T_{vj} = 125\text{ }^{\circ}\text{C}$		3.10		V
I_{SC}	短路电流 Short circuit current	$T_{vj} = 125\text{ }^{\circ}\text{C}, V_{CC} = 3400V,$ $V_{GE} \leq 15V, t_p \leq 10\mu s,$ $V_{CE(max)} = V_{CES} - L \times di/dt,$ IEC 60747-9		21000		A



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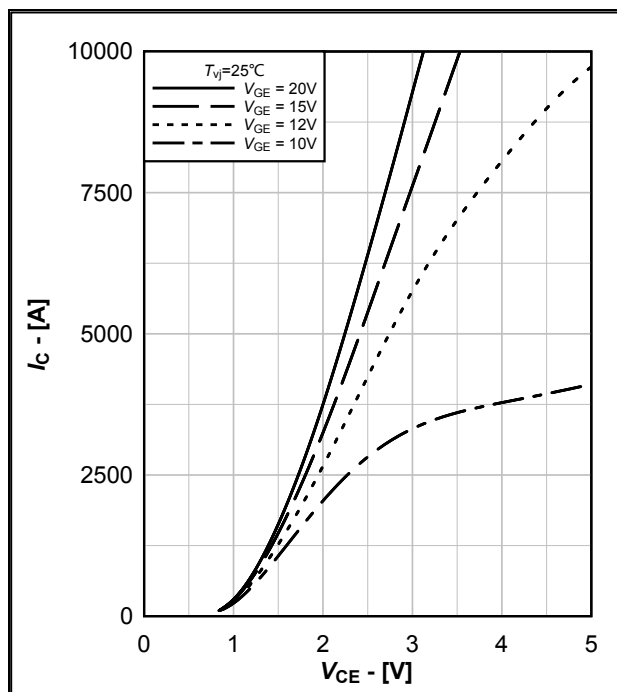
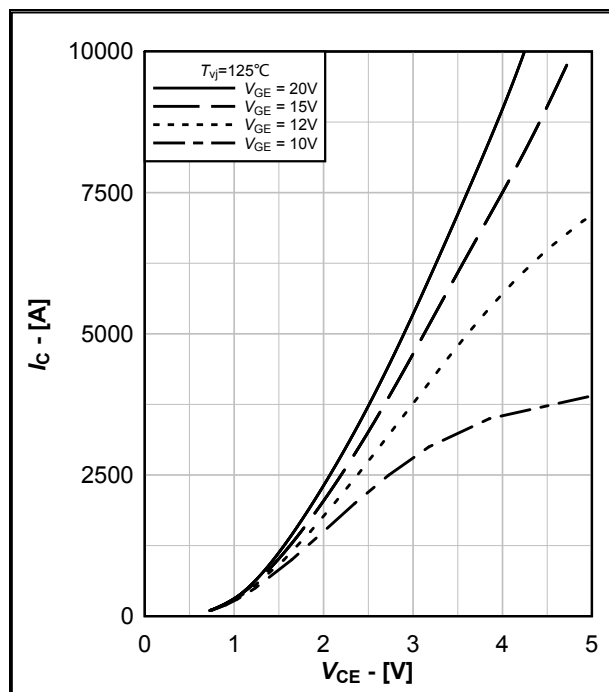
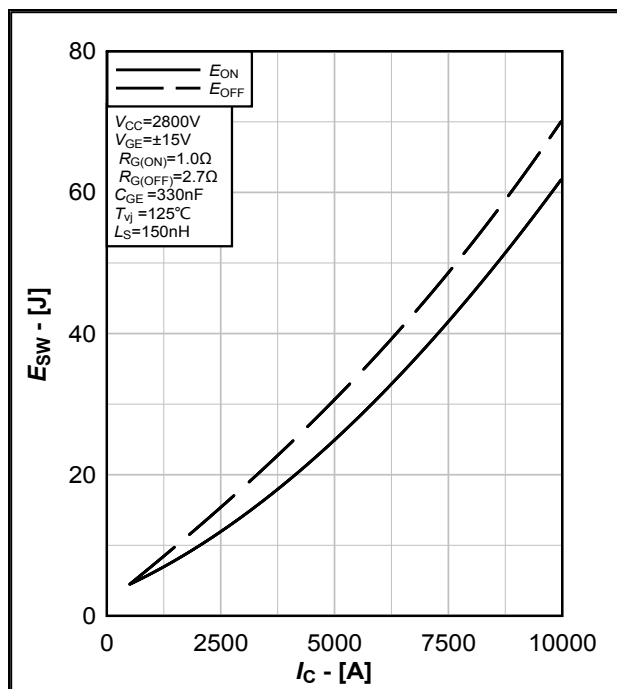
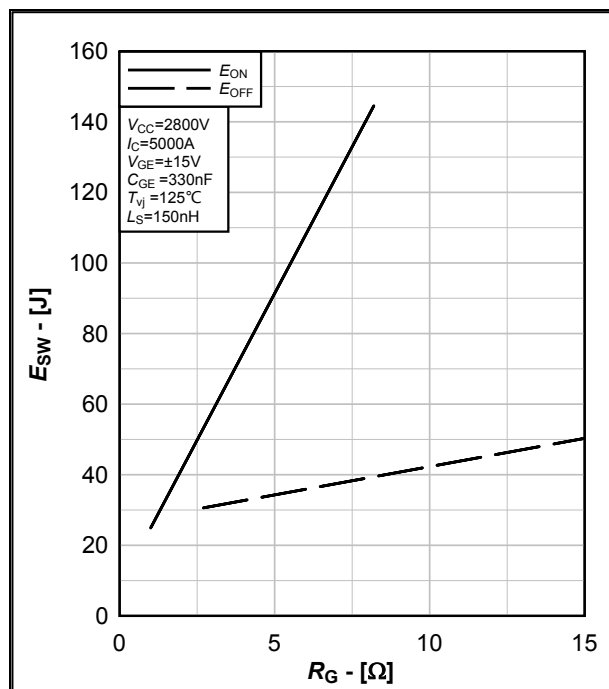
Electrical Characteristics

除非特别声明, 否则 $T_C = 25\text{ }^{\circ}\text{C}$ $T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise stated

符号 Symbol	参数名称 Parameter	条件 Test Conditions	最小值 Min.	典型值 Typ.	最大值 Max.	单位 Unit
C_{ies}	输入电容 Input capacitance	$V_{CE} = 25V, V_{GE} = 0V, f = 100kHz$		788		nF
Q_g	栅极电荷 Gate charge	$\pm 15V$		49		μC
C_{res}	反向传输电容 Reverse transfer capacitance	$V_{CE} = 25V, V_{GE} = 0V, f = 100kHz$		9.3		nF
C_{oes}	输出电容 Output capacitance	$V_{CE} = 25V, V_{GE} = 0V, f = 100kHz$		31		nF
L_{sCE}	模块电感 Module inductance			1.5		nH

电特性值
Electrical Characteristics

符号 Symbol	参数名称 Parameter	条件 Test Conditions		最小值 Min.	典型值 Typ.	最大值 Max.	单位 Unit
$t_{d(off)}$	关断延迟时间 Turn-off delay time	$I_C = 5000A$, $V_{CE} = 2800V$, $V_{GE} = \pm 15V$, $R_{G(OFF)} = 2.7\Omega$, $C_{GE} = 330nF$, $L_S = 150nH$ Diode: TG5000SF45Z C-D200	$T_{vj} = 25\text{ }^{\circ}\text{C}$		4880		ns
			$T_{vj} = 125\text{ }^{\circ}\text{C}$		5070		
t_f	下降时间 Fall time		$T_{vj} = 25\text{ }^{\circ}\text{C}$		1555		ns
			$T_{vj} = 125\text{ }^{\circ}\text{C}$		2910		
E_{OFF}	关断损耗 Turn-off energy loss		$T_{vj} = 25\text{ }^{\circ}\text{C}$		27.0		J
			$T_{vj} = 125\text{ }^{\circ}\text{C}$		30.6		
$t_{d(on)}$	开通延迟时间 Turn-on delay time	$I_C = 5000A$, $V_{CE} = 2800V$, $V_{GE} = \pm 15V$, $R_{G(ON)} = 1.0\Omega$, $C_{GE} = 330nF$, $L_S = 150nH$, $di/dt = 7000A/\mu s$, ($T_{vj} = 125\text{ }^{\circ}\text{C}$) Diode: TG5000SF45Z C-D200	$T_{vj} = 25\text{ }^{\circ}\text{C}$		1685		ns
			$T_{vj} = 125\text{ }^{\circ}\text{C}$		1680		
t_r	上升时间 Rise time		$T_{vj} = 25\text{ }^{\circ}\text{C}$		700		ns
			$T_{vj} = 125\text{ }^{\circ}\text{C}$		750		
E_{ON}	开通损耗 Turn-on energy loss		$T_{vj} = 25\text{ }^{\circ}\text{C}$		19.4		J
			$T_{vj} = 125\text{ }^{\circ}\text{C}$		24.9		

图 3. IGBT 输出特性典型曲线, $I_c = f(V_{CE})$ Fig.3 Typical IGBT output characteristics, $I_c = f(V_{CE})$ 图 4. IGBT 输出特性典型曲线, $I_c = f(V_{CE})$ Fig.4 Typical IGBT output characteristics, $I_c = f(V_{CE})$ 图 5. IGBT 开关能耗典型曲线, $E_{ON} = f(I_c)$, $E_{OFF} = f(I_c)$ Fig.5 Typical IGBT switching energy, $E_{ON} = f(I_c)$, $E_{OFF} = f(I_c)$ 图 6. IGBT 开关能耗典型曲线, $E_{ON} = f(R_G)$, $E_{OFF} = f(R_G)$ Fig.6 Typical IGBT switching energy, $E_{ON} = f(R_G)$, $E_{OFF} = f(R_G)$

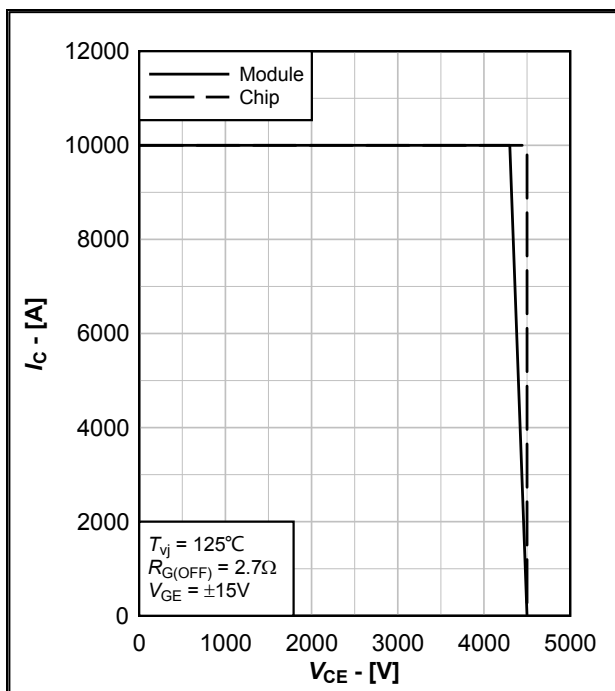


图 7. IGBT 反偏安全工作区, $I_C = f(V_{CE})$

Fig.7 Reverse bias safe operating area of IGBT, $I_C = f(V_{CE})$

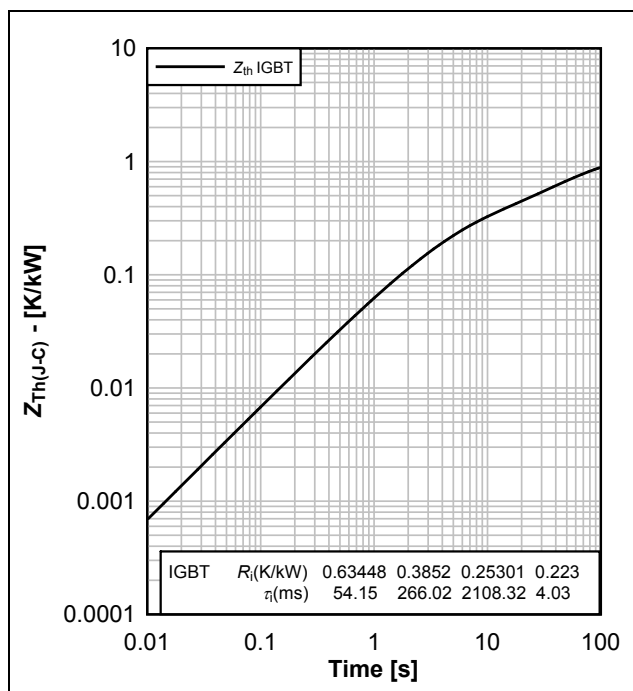
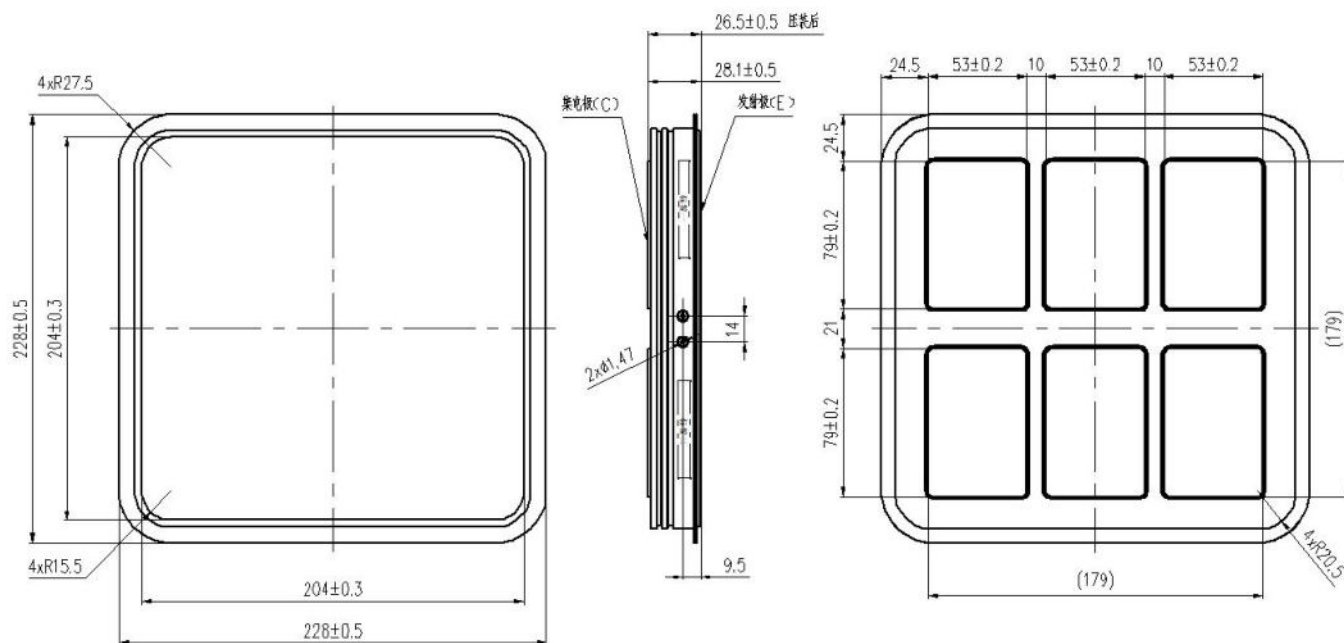


图 8. 瞬态热阻抗曲线, $Z_{th(j-c)} = f(t_p)$

Fig.8 Transient thermal impedance, $Z_{th(j-c)} = f(t_p)$



重量 Weight: 4000g

模块外观类型 Module outline code: ZF

图 9. 模块外观尺寸

Fig. 9 Module outlines

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